

# United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/475,262	12/30/1999	BEN D. ROBERTS	042390.P6809	6144
7:	590 04/09/2003			
DARREN J MILLIKEN BLAKELY SOKOLOFF TAYLOR & ZAFMAN LLP 7TH FLOOR 12400 WILSHIRE BOULEVARD LOS ANGELES, CA 90025			EXAMINER	
			CRAIG, DWIN M	
			ART UNIT	PAPER NUMBER
2007HVGEEE	, 0.11 > 0025		2123	3
		DATE MAILED: 04/09/2003		

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No	Applicant(s) DRL				
•	09/475,262	ROBERTS, BEN D.				
Office Action Summary	Examiner	Art Unit				
	Dwin M Craig	2123				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).  Status						
1) Responsive to communication(s) filed on 30 E	<u> Pecember 1999</u> .					
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ Thi	s action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims						
4)⊠ Claim(s) <u>1-63</u> is/are pending in the application						
4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1-63</u> is/are rejected.						
7), 1 Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9) The specification is objected to by the Examiner						
10)⊠ The drawing(s) filed on <u>30 December 1999</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) ☐ The proposed drawing correction filed on is: a) ☐ approved b) ☐ disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12)☐ The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) ☐ All b) ☐ Some * c) ☐ None of:						
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority documents have been received in Application No						
<ul> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).						
a) ☐ The translation of the foreign language provisional application has been received.						
15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment(s)						
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statement(s) (PTO-1449) Paper No(s) 2</li> </ol>	5) Notice of Info	nmary (PTO-413) Paper No(s) rmal Patent Application (PTO-152)				
S. Patent and Trademark Office		<del></del>				

Art Unit: 2123

#### **DETAILED ACTION**

1. Claims 1-63 have been presented for examination. Claims 1-63 have been examined and rejected.

#### Claim Objections

2. Claim 17 is objected to because of the following informalities: in line 3 at the end of the sentence there is the phrase "resistors <u>is</u> series" this phrase should be changed to "resistors <u>in</u> series". Appropriate correction is required.

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1-3, 5-13, 15-20, 22-35, 37-45, 47-52 and 54-63 are rejected under 35 U.S.C. as being unpatentable over Nakamura U.S. Patent 6,192,330 in view of Muddu U.S. Patent 6,314,546 and in further view of Dannsky et al. U.S. Patent 6,028,989.
- 3.1 As regards independent Claims 1, 18, 28, 29, 33, 50 and 60 the *Nakamura* reference discloses, a machine readable storage medium with at least one processor (Figure 35 Item 6, Col. 7 Lines 39-50), and a string model (Figures 3, 5, 6, 9, 22A, 22B, 23, 24, 25, 26, 27, 28, 30A, 30B, 30C, 34).

Art Unit: 2123

However, the *Nakamura* reference does not expressly disclose modeling a trace lumped elements, cross capacitors, a pi model and applied noise voltage.

The Muddu reference discloses modeling a trace (Figure 1), a pi model (Figures 8b, 8c).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

The *Nakamura* reference does not expressly disclose lumped elements, cross capacitors and applied noise voltage.

The Dannsky et al. reference discloses lumped elements (Col. 7 Lines 9-67, Col. 8 Lines 1-6) cross capacitors (Col. 7 Line 16), and applied noise voltage (Col. 1 Lines 15-18, Lines 63-67, Col. 2 Lines 1-17).

It would have been obvious to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Dannsky et al.* reference because (motivation to combine) it is important to calculate in an efficient manner the voltage noise characteristics of an integrated circuit design (Dannsky et al. Col. 1 Lines 55-67, Col. 2 Lines 1-33).

3.2 As regards the limitation disclosed in independent Claim 28 regarding an apparatus, the *Nakamura* reference discloses (Figure 35).

Art Unit: 2123

3.3 As regards Claims 2, 3, 5, 19, 20, 22, 23, 34, 35, 37, 51, 52 and 54 the *Nakamura* does not expressly disclose reducing the number of capacitors and resistors in the model and the O'Brien/Savarino method.

The *Muddu* reference discloses reducing the number of capacitors and resistors in the model and the O'Brien/Savarino method, (Figure 4, Col. 5 Lines 35-67, Col. 6 Lines 1-67, Col. 7 Lines 1-2).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

3.4 As regards Claims 6, 38 and 55 the *Nakamura* reference does not expressly disclose a "pi" model.

The Muddu reference discloses a "pi" model (Figure 8b and 8c).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

Art Unit: 2123

3.5 As regards Claims 7, 32, 39, 56 and 63 the *Nakamura* reference does not expressly disclose a voltage ramp.

The Muddu reference discloses a voltage ramp (Figure 2b).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

3.6 As regards Claims 8, 24 and 40 the *Nakamura* reference does not expressly disclose a ramp time and a driving transistor.

The *Muddu* reference discloses a ramp time and a driving transistor (Figures 1, 2a, 2b, 3, 4, 5a, 5b, 6a, 6b, 7a, 7b, 8a, 8b, 8c, 8d and 8e, Col. 3 Lines 44-67, Col. 4 Lines 1-67, Col. 5 Lines 1-67, Col. 6 Lines 1-67, Col. 7 Lines 1-2).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

3.7 As regards Claims 9 and 41 the *Nakamura* reference does disclose a string model, however it does not expressly disclose a pi model.

Art Unit: 2123

The Muddu reference discloses a pi model (Figures 8b, 8c).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

3.8 As regards Claims 10 and 42 the *Nakamura* reference does not expressly disclose a linear source.

The *Muddu* reference discloses a linear source model (Figures 8a, 8c, Col. 8 Lines 8-14).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

3.9 As regards Claims 11, 12, 43, 44 and 57 the *Nakamura* reference does not expressly disclose a victim node of the pi model.

The Dansky et al. reference discloses a victim node of the pi model (Col. 1 Lines 24-26, Col. 3 Lines 15-16, Col. 3 Lines 40-48).

Art Unit: 2123

It would have been obvious to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Dannsky et al.* reference because *(motivation to combine)* it is important to calculate in an efficient manner the voltage noise characteristics of an integrated circuit design *(Dannsky et al. Col. 1 Lines 55-67, Col. 2 Lines 1-33)*.

3.10 As regards Claims 13, 26, 27, 58 and 59 the *Nakamura* reference does not expressly disclose a second noise voltage to the pi model.

The Dansky et al. reference discloses a second noise voltage applied to the pi model (Col. 3 Lines 40-49).

It would have been obvious to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Dannsky et al.* reference because (motivation to combine) it is important to calculate in an efficient manner the voltage noise characteristics of an integrated circuit design (Dannsky et al. Col. 1 Lines 55-67, Col. 2 Lines 1-33).

3.11 As regards Claims 15, 16 and 25 the *Nakamura* reference does not expressly disclose calculating the peak noise.

The Dansky et al. reference discloses calculating peak noise (Col. 7 Lines 60-67, Col. 8 Lines 1-6).

It would have been obvious to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Dannsky et al.* reference because (motivation to combine) it is important to calculate in an efficient manner the voltage noise characteristics of an integrated circuit design (Dannsky et al. Col. 1 Lines 55-67, Col. 2 Lines 1-33).

Art Unit: 2123

3.12 As regards Claims 17 and 49 the *Nakamura* reference does not expressly disclose resistors in series and capacitors in parallel reduced into a pi-model.

The *Muddu* reference discloses resistors in series (Figure 5a, 5b, Col. 6 Lines 15-25) and capacitors in parallel (Figures 8b, 8c).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

3.13 As regards Claims 30 and 61 the *Nakmura* reference does not expressly disclose discrete samples.

The Mudda reference discloses discrete load capacitances (Col. 4 Lines 14-22).

It would have been obvious, to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Muddu* reference because (motivation to combine) when designing with sub-micron design rules for integrated circuit design accurate models for interconnect delay of logic gates are required for functional models that reflect the true functioning on the silicon substrate before expensive fabrication is performed, (Muddu, Col. 1 Lines 15-67, Col. 2 Lines 1-50).

3.14 As regards Claims 31, 45, 47, 48 and 62 the *Nakamura* reference does not expressly disclose applied noise voltage.

Art Unit: 2123

The *Dannsky et al.* reference discloses applied noise voltage (Col. 1 Lines 15-18, Lines 63-67, Col. 2 Lines 1-17).

It would have been obvious to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Dannsky et al.* reference because (motivation to combine) it is important to calculate in an efficient manner the voltage noise characteristics of an integrated circuit design (Dannsky et al. Col. 1 Lines 55-67, Col. 2 Lines 1-33).

- 4. Claims 4, 21, 36 and 53 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakamura U.S. Patent 6,192,330 in view of Muddu U.S. Patent 6,314,546 and in further view of Dannsky et al. U.S. Patent 6,028,989 and in further view of "Modeling the Driving-Point Characteristics of Resistive Interconnect for Accurate Delay Estimation", Peter R. O'Brien and Thomas L. Savarino, IEEE 1989 hereafter referred as the O'Brien and Savarino reference.
  - 4.1 As regards independent Claims 1, 18, 33, 50 see the rejection in paragraph 3.1.
- 4.2 As regards dependent Claims 2, 3, 19, 20, 34, 35, 51 and 52 see the rejection in paragraph 3.3.
- 4.3 As regards Claims 4, 21, 36, 53 the *Nakamura* reference does not expressly disclose the Elmore influence reduction method.

The O'Brien and Savarino reference discloses the Elmore influence reduction method (pages 513-514).

It would have been obvious to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *O'Brien and Savarino* reference

Art Unit: 2123

because (motivation to combine) the methods disclosed in the O'Brien and Savarino reference provides greater accuracy in determining the voltage transfer ration between gates in an integrated circuit, (Abstact, Page 512 "Modeling the Driving-Point Characteristics of Resistive Interconnect for Accurate Delay Estimation", Peter R. O'Brien and Thomas L. Savarino, IEEE 1989).

- 5. Claims 14 and 46 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakamura U.S. Patent 6,192,330 in view of Muddu U.S. Patent 6,314,546 and in further view of Dannsky et al. U.S. Patent 6,028,989 and in further view of Arsenault et al. U.S. Patent 6,396,256.
  - 5.1 As regards independent Claims 1 and 33 see the rejection in paragraph 3.1.
- 5.2 As regards dependent Claims 13 and 45 see the rejection in paragraph 3.10 and3.14 respecively.
- 5.5 As regards Claims 14 and 46 the *Nakamura* reference does not expressly disclose voltage ramps having their ramp times in phase.

The Arsenault et al. reference discloses voltage ramps having their ramp times in phase (Figures 2 and 3, Col. 1 Lines 45-55, Col. 2 Lines 48-63).

It would have been obvious to one of ordinary skill in the art, at the time of the invention, to have modified the *Nakamura* reference with the *Arsenault et al.* reference because (motivation to combine) the *Arsenault et al.* reference discloses a method of detecting defects in a design before manufacturing and therefore remove the requirement to have to redesign a product after the initial investment in manufacturing has been made, (Arsenault et al. Col. 1 Lines 34-45).

Page 11

Application/Control Number: 09/475,262

Art Unit: 2123

### Conclusion

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dwin M Craig whose telephone number is 703 305-7150. The examiner can normally be reached on 9:00 - 5:00 M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kevin Teska can be reached on 703 305-9704. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 746-7239 for regular communications and (703) 746-7238 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703 305-3900.

DMC April 2, 2003

> RUSSELL FREJD PRIMARY EXAMINER